



Integrated Circuit Solution for Active Antennas

DATASHEET

Features

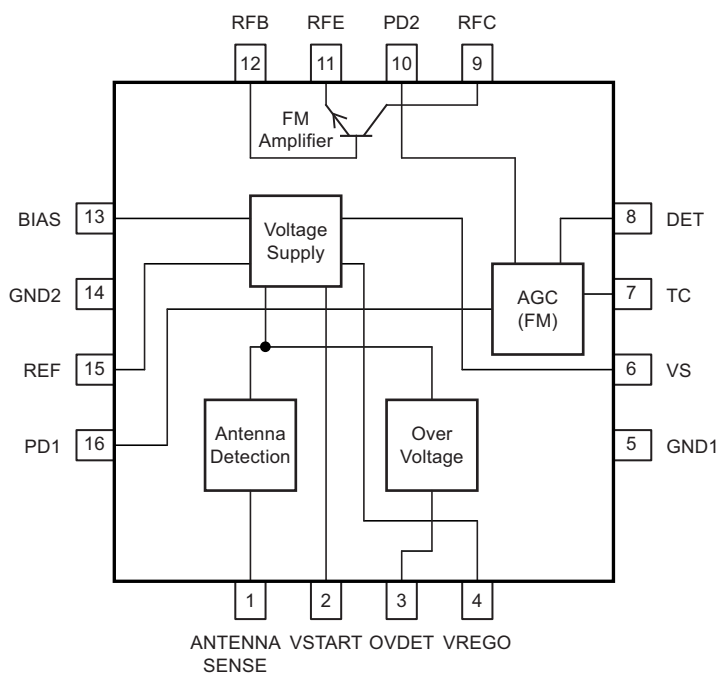
- Highly integrated - All-in-one active antenna IC
- Operating frequency range: 50MHz to 900MHz
- Main application 76MHz to 108MHz (broadcast FM worldwide)
- Integrated AGC
- Integrated driver for PIN diodes
- Integrated power supply regulator
- Integrated antenna sensor
- High dynamic range
- Excellent noise performance
- High intercept point 3rd order
- RF amplifier adjustable to various cable impedances
- Low noise output voltage
- Low power consumption

1. Description

The Atmel® ATR4253C is a highly integrated high-performance IC for active antenna amplification. The device has a built-in AGC, antenna detection, a power supply regulator and two driver stages for external PIN diodes.

The Atmel ATR4253C is based on BICMOS technology. The device is designed in particular for car applications and is suitable for active antennas located in several positions within the car such as bumpers, windscreen, mirrors or windows.

Figure 1-1. Block Diagram



2. Pin Configuration

Figure 2-1. Pinning QFN 3x3 / 16 Pins

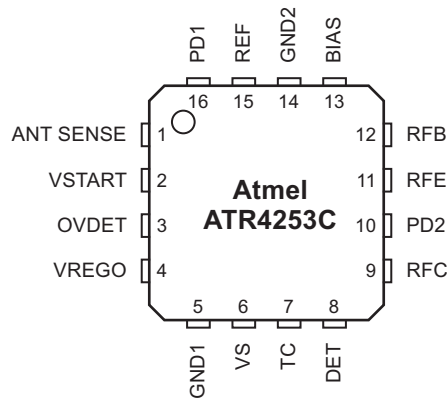


Table 2-1. Pin Description

Pin	Symbol	Function
1	ANT SENSE	Antenna sense input
2	VSTART	Comparator input of voltage detector
3	OVDET	Overvoltage detection input
4	VREGO	Voltage regulator output
5	GND1	Ground voltage regulator
6	VS	Supply voltage
7	TC	AGC time constant
8	DET	AGC level detector input
9	RFC	Amplifier Collector (NPN)
10	PD2	2 nd AGC output for pin diode
11	RFE	Amplifier emitter (NPN)
12	RFB	Amplifier base (NPN)
13	BIAS	Bias voltage (2.7V)
14	GND2	Ground FM
15	REF	Reference voltage (6V)
16	PD1	1 st FM AGC output for pin diode
Paddle	GND	Ground paddle

3. Functional Description

The Atmel® ATR4253C is a highly integrated antenna amplifier with a broad range of features and functions. It compensates cable losses between the antenna and the car radio, which is usually placed far away from the antenna. The device can be used in the frequency range of 50MHz up to 900MHz (i.e., FM, DAB (+), DMB, DVB-T, ISDB-T, etc.) and has the flexibility to address different antenna types (e.g., glass, windscreen, roof antennas).

A separate automatic gain control (AGC) function is integrated in order to avoid overdriving the RF amplifier at large signal conditions.

The integrated PIN diode drivers help to reduce the external component cost and to minimize the board space.

The external component cost can be further reduced as the voltage regulation stage is also integrated. This stage provides overvoltage protection and current limitation. An external transistor is used as power driver for this stage.

3.1 RF Amplifier Stage

The RF amplifier is realized with a high-performance NPN transistor. This allows the use of an amplifier configuration which is optimized for the individual application requirements. For low-cost applications, the common emitter configuration enables good performance at reasonable BOM cost. For high-end applications, a common base configuration with transformer feedback provides high IP3 and low noise figures at reasonable current consumption. In both configurations, gain, input and output impedance can be adjusted by modifying the external components.

The bias voltage (BIAS) for the base of the NPN transistor is derived from an integrated voltage reference and has a PTAT (proportional to absolute temperature) behavior. The bias current of the RF amplifier is defined by an external resistor and is kept constant over temperature.

3.2 AGC

The IC is equipped with an AGC functionality to prevent overdriving the amplifier in case the amplifier is operated at strong antenna signals, e.g., near transmitters. It is possible to realize an additional antenna amplifier path with integrated AGC and external RF transistor. The bandwidth of the integrated AGC circuit is 900MHz.

The amplifier output (RFC) is connected to a capacitive voltage divider and the divided signal is applied to the AGC level detector at pin DET. This level detector input is optimized for low distortion. The rectified signal is compared against an internal reference. The divider ratio of the external voltage divider defines the AGC's threshold. If the threshold is reached, pin PD1 drives a positive current through one or two external pin diodes in shunt configuration. In case the limiting range of the shunt configuration is not sufficient an additional pin diode in serial configuration can be added and controlled via pin PD2. The current from PD2 through the serial pin diode is opposite to the current of PD1. This helps to limit the amplifier input signal and thus to prevent the FM amplifier from signal overdrive.

The drivers required for the external pin diode(s) are built-in into the Atmel ATR4253C IC, which reduces the BOM cost and the application size.

3.3 Supply Voltage Regulator

The driving voltage for an external power transistor is provided by an integrated regulator circuit.

An overvoltage protection circuit detects overvoltage condition and switches off the amplifier and AGC circuit in order to reduce current consumption and avoid thermal overload.

3.4 Antenna Sensor

The Atmel® ATR4253C provides a built-in antenna sensor that detects if the antenna is properly connected to the amplifier module. If no antenna is detected, the amplifier and AGC circuit are switched off to signal this error via supply current reduction to the unit that provides and monitors the supply current for the antenna amplifier (e.g., the car radio).

4. Absolute Maximum Ratings

Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Parameters	Pin	Symbol	Min.	Max.	Unit
Supply voltage	6	V_S	−0.3	+12	V
Antenna sense current	1	ANT SENSE	−500	+500	μA
Comparator input current	2	VSTART	0	2	mA
Overvoltage detector	3	OVDET	−0.3	+3.3	V
Collector of FM amplifier	9	RFC	3	16	V
Power dissipation		P_{tot}		700	mW
Junction temperature		T_j		150	°C
Ambient temperature		T_{amb}	−40	+115	°C
Storage temperature		T_{stg}	−50	+150	°C
ESD HBM	All	V_{HBM}	−2	+2	kV

5. Thermal Resistance

Parameters	Symbol	Value	Unit
Junction ambient, soldered on PCB, dependent on PCB layout	R_{thJA}	40	K/W

6. Operating Range

Parameters	Test Conditions	Pin	Symbol	Min.	Typ.	Max.	Unit
Supply voltage	Normal operation	6	V_S	7.5	10	11	V
Supply voltage	Performance may be reduced, no malfunction	6	V_S	7		11	V
FM emitter current	Thermal condition	11	I_{RFE}			35	mA

7. Electrical Characteristics

See test circuit (Figure 8-2 on page 9), $V_S = 10V$, $T_{amb} = 25^\circ C$, unless otherwise specified.

No.	Parameters	Test Conditions	Pin	Symbol	Min.	Typ.	Max.	Unit	Type*
1.1	Supply current	AGC OFF	VS	I_S		12		mA	B
		AGC ON ; includes 7mA pin diode current	VS	I_S		19		mA	B
		Antenna sense error detected	VS	I_S	15	20	25	mA	A
		Over voltage	VS	I_S		10	14.9	mA	A
		$T_{amb} = -40$ to $+115^\circ C$; AGC ON; includes 7mA pin diode current and 31mA RF current	VS, RFC	I_S, I_{RFC}		50	70	mA	C
1.2	Bias voltage output		BIAS	V_{BIAS}	2.5	2.8	3.1	V	A
1.3	Output current of bias voltage		BIAS	I_{BIAS}	0		3	mA	B
1.5	Bias voltage output	1k Ω output resistor	REF	V_{REF}	5.7	6	6.3	V	A
2	RF Amplifier								
2.1	Emitter voltage	$T = 25^\circ C$	RFE		2.0	2.1	2.2	V	A
2.2	Emitter voltage	$T = -40^\circ C$ to $+115^\circ C$	RFE		1.9	2.1	2.3	V	C
2.3	Supply current ⁽¹⁾	Common base	RFC	I_{RFC}		31		mA	B
2.4	Supply current ⁽²⁾	Common emitter	RFC	I_{RFC}		35		mA	A
2.5	Maximum output voltage	$V_S = 10V$	RFC		12			V_{pp}	C
2.6	Input resistance	$f = 100MHz$	RF IN	R_{FMIN}		50		Ω	C
2.7	Output resistance	$f = 100MHz$	RF OUT	R_{FMOUT}		50		Ω	C
2.8	Power gain	$f = 100MHz$	RF IN, RF OUT	G		5.2		dB	C
2.9	OIP3 at FMOUT	Common base	RF OUT			146		dB μV	C
2.10	NF	Common base	RF OUT			1.6		dB	C
2.11	Power gain	$f = 100MHz$, common emitter	RF OUT	G		13.5		dB	B
2.12	OIP3 at FMOUT	Common emitter	RF OUT			140		dB μV	B
2.13	NF	Common emitter	RF OUT			3.5		dB	C
2.14	Maximum operating frequency	3dB corner, common emitter	RF OUT		450			MHz	C
3	AGC								
3.1	AGC input voltage threshold	FM range: $f = 100MHz$	DET	$V_{th1,100}$	83	85	87	dB μV	B
		Extended: $f = 900MHz$		$V_{th1,900}$	81	85	89	dB μV	C
3.2	Saturation voltage	10mA	PD1,2			VS – 2.0		V	B
3.3	Leakage current		PD1,2				1	μA	B
3.4	Maximum pin diode current	AGC active, $115^\circ C$	PD1		12	19		mA	D
3.5	Maximum pin diode current	AGC not active	PD2		12			mA	A

*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

Notes: 1. Current defined by R11= 68 Ω

2. Current defined by R11= 56 Ω

7. Electrical Characteristics (Continued)

See test circuit (Figure 8-2 on page 9), $V_S = 10V$, $T_{amb} = 25^\circ C$, unless otherwise specified.

No.	Parameters	Test Conditions	Pin	Symbol	Min.	Typ.	Max.	Unit	Type*
3.6	Input resistance		DET	R_{DET}	17		25	$k\Omega$	C
3.7	Input capacitance	$f = 100MHz$	DET	C_{DET}	1.5		2.0	pF	C
3.8	IP3 Pin 8 FM	100MHz + 105MHz, $V_{DET} = 120dB\mu V$	DET			150		$dB\mu V$	C
3.9	Transconductance	dI_{FMTc} / dV_{FMDet}	TC DET	dI_{TC} / dV_{DET}	0.35	0.5	0.8	mA/V (rms)	B
4	Voltage Regulator / Monitor								
4.1	Output voltage of regulator	Battery voltage $V_B = 14V$	VS		9.5	10	10.5	V	A
4.2	Ripple rejection of regulator	100Hz, $V_B > V_S + 1V$	VB, RF OUT		40	50		dB	C
4.3	Threshold for over-voltage detection		OVDET		1.6		1.8	V	A
4.4	Hysteresis of overvoltage detection		OVDET			5		%	C
5	Antenna Sensor								
5.1	Antenna monitor range	$R_{SENSE} = 22k\Omega$, antenna detected	ANT SENS		0 to 3		6 to 16	V	C

*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

- Notes:
1. Current defined by $R11 = 68\Omega$
 2. Current defined by $R11 = 56\Omega$

8. Application Circuits

Figure 8-1. Common Emitter Configuration

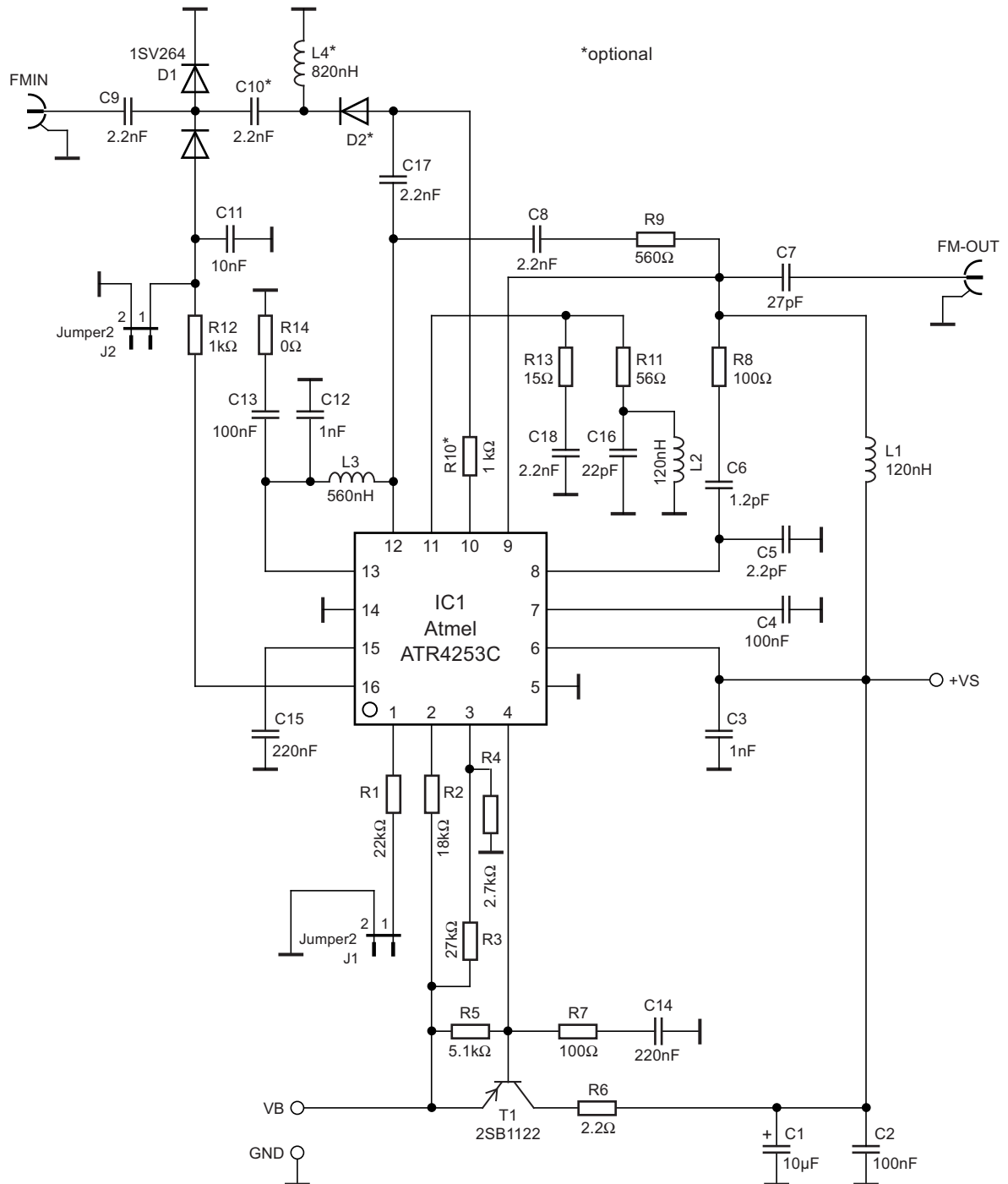


Figure 8-2. Common Base Configuration

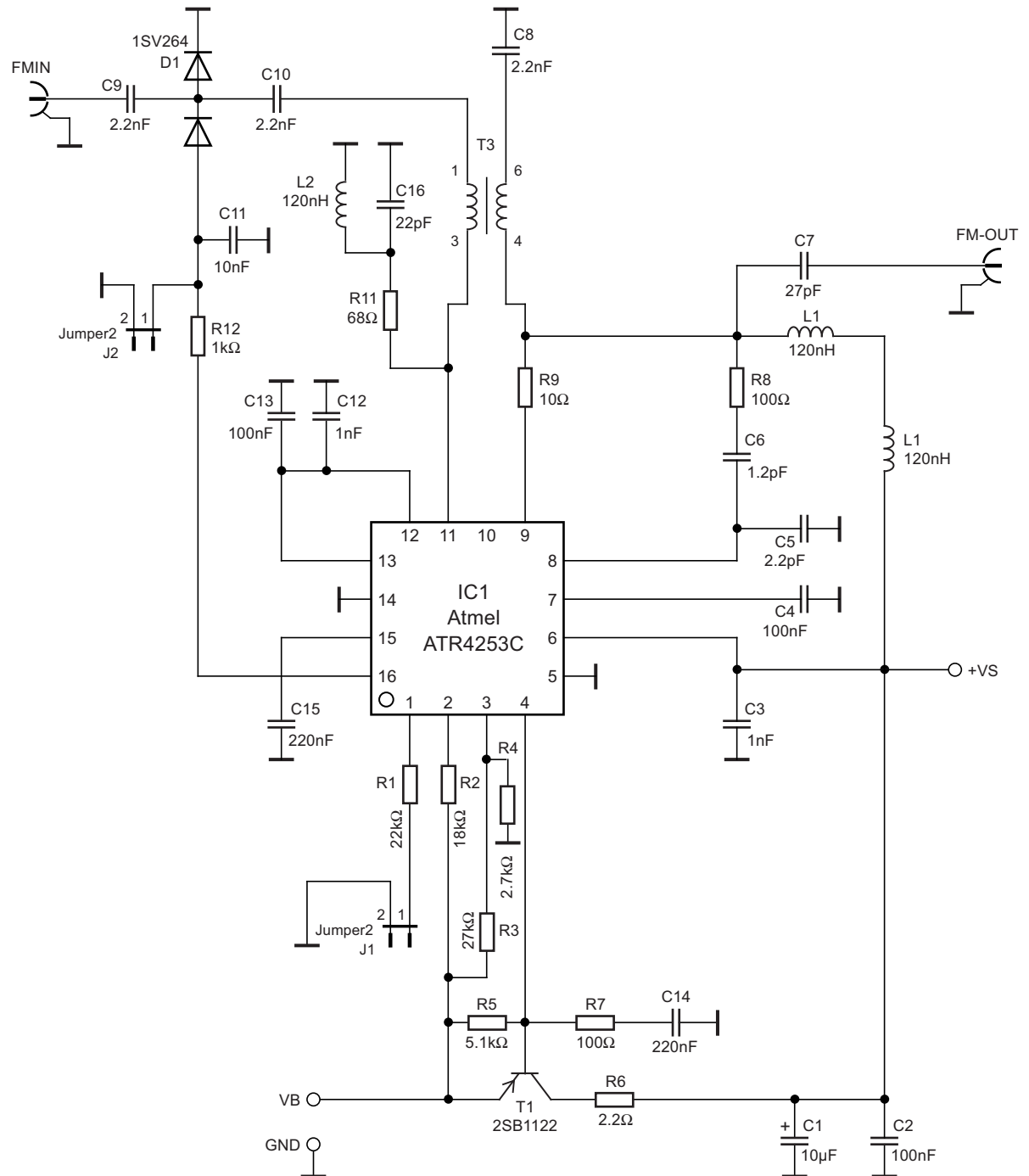
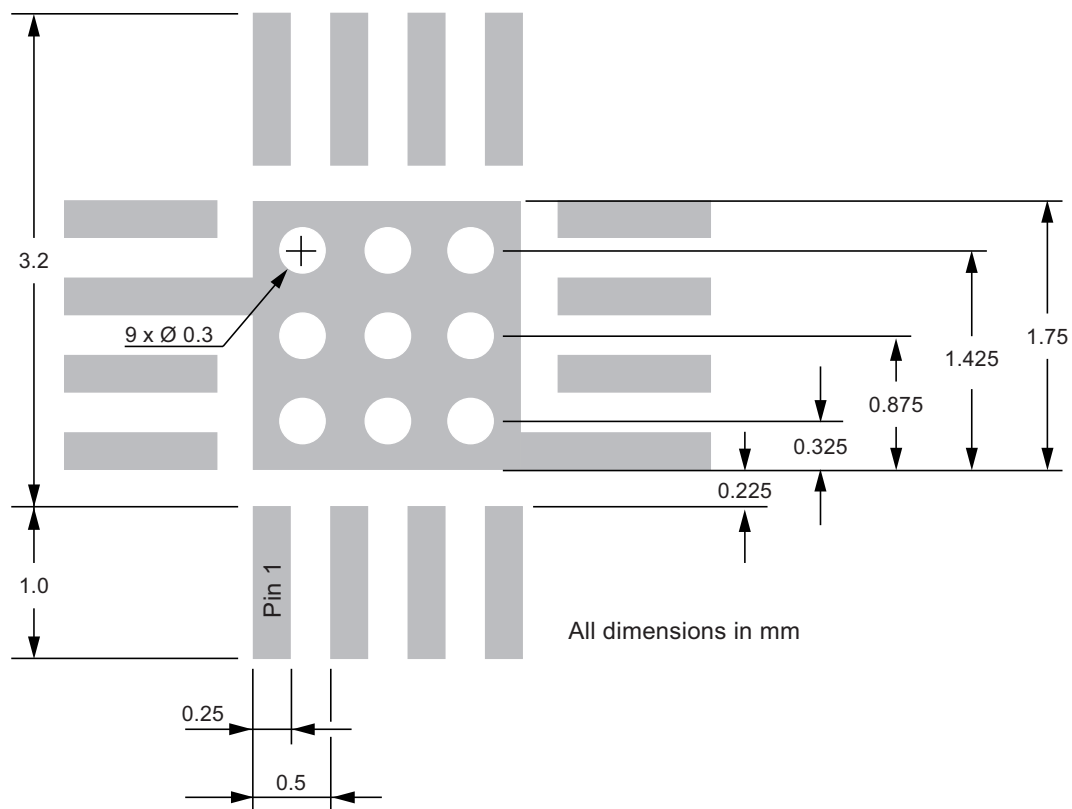


Figure 8-3. Recommended Footprint

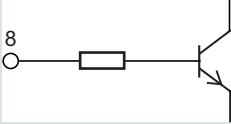
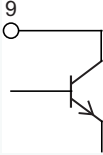
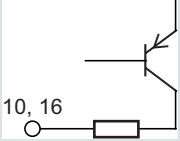
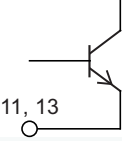
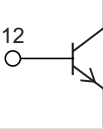
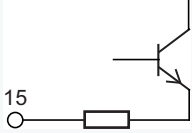


9. Internal Circuitry

Table 9-1. Equivalent Pin Circuits (ESD Protection Circuits not Shown)

Pin	Symbol	Function
1	ANT SENSE	
2	VSTART	
3	OVDET	
4	VREGO	
5, 14	GND1, GND2	
6	VS	
7	TC	

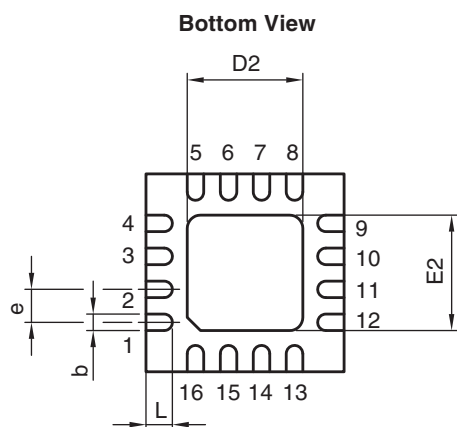
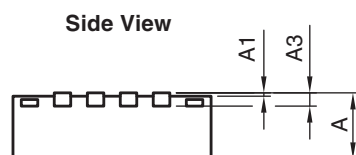
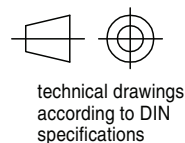
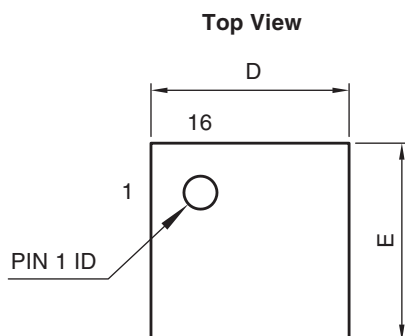
Table 9-1. Equivalent Pin Circuits (ESD Protection Circuits not Shown) (Continued)

Pin	Symbol	Function
8	DET	
9	RFC	
10, 16	PD1, PD2	
11, 13	RFE, BIAS	
12	RFB	
15	REF	

10. Ordering Information

Extended Type Number	Package	Remarks
ATR4253C-PVPW	VQFN 3x3 / 16L	Taped on reel, 2k volume
ATR4253C-PVQW	VQFN 3x3 / 16L	Taped on reel, 8k volume

11. Package Information



COMMON DIMENSIONS (Unit of Measure = mm)				
Symbol	MIN	NOM	MAX	NOTE
A	0.8	0.9	1	
A1	0.0	0.02	0.05	
A3	0.15	0.2	0.25	
D	2.9	3	3.1	
D2	1.7	1.75	1.8	
E	2.9	3	3.1	
E2	1.7	1.75	1.8	
L	0.3	0.4	0.5	
b	0.18	0.25	0.32	
e		0.5 BSC		

11/11/09



Package Drawing Contact:
packagedrawings@atmel.com

TITLE
Package: VQFN_3x3_16L
Exposed pad 1.75 x 1.75

DRAWING NO.
6.543-5164.01-4

REV.
1



Enabling Unlimited Possibilities™

Atmel Corporation

2325 Orchard Parkway
San Jose, CA 95131
USA

Tel: (+1) (408) 441-0311

Fax: (+1) (408) 487-2600

www.atmel.com

Atmel Asia Limited

Unit 01-5 & 16, 19F
BEA Tower, Millennium City 5
418 Kwun Tong Roa
Kwun Tong, Kowloon

HONG KONG

Tel: (+852) 2245-6100

Fax: (+852) 2722-1369

Atmel Munich GmbH

Business Campus
Parking 4
D-85748 Garching b. Munich
GERMANY

Tel: (+49) 89-31970-0

Fax: (+49) 89-3194621

Atmel Japan G.K.

16F Shin-Osaki Kangyo Building
1-6-4 Osaki
Shinagawa-ku, Tokyo 141-0032
JAPAN

Tel: (+81) (3) 6417-0300

Fax: (+81) (3) 6417-0370

© 2011 Atmel Corporation. All rights reserved. / Rev.: 9265A-AUDR-08/12

Atmel®, Atmel logo and combinations thereof, Enabling Unlimited Possibilities®, and others are registered trademarks or trademarks of Atmel Corporation or its subsidiaries. Other terms and product names may be trademarks of others.

Disclaimer: The information in this document is provided in connection with Atmel products. No license, express or implied, by estoppel or otherwise, to any intellectual property right is granted by this document or in connection with the sale of Atmel products. EXCEPT AS SET FORTH IN THE ATMEL TERMS AND CONDITIONS OF SALES LOCATED ON THE ATMEL WEBSITE, ATMEL ASSUMES NO LIABILITY WHATSOEVER AND DISCLAIMS ANY EXPRESS, IMPLIED OR STATUTORY WARRANTY RELATING TO ITS PRODUCTS INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTY OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, OR NON-INFRINGEMENT. IN NO EVENT SHALL ATMEL BE LIABLE FOR ANY DIRECT, INDIRECT, CONSEQUENTIAL, PUNITIVE, SPECIAL OR INCIDENTAL DAMAGES (INCLUDING, WITHOUT LIMITATION, DAMAGES FOR LOSS AND PROFITS, BUSINESS INTERRUPTION, OR LOSS OF INFORMATION) ARISING OUT OF THE USE OR INABILITY TO USE THIS DOCUMENT, EVEN IF ATMEL HAS BEEN ADVISED OF THE POSSIBILITY OF SUCH DAMAGES. Atmel makes no representations or warranties with respect to the accuracy or completeness of the contents of this document and reserves the right to make changes to specifications and products descriptions at any time without notice. Atmel does not make any commitment to update the information contained herein. Unless specifically provided otherwise, Atmel products are not suitable for, and shall not be used in, automotive applications. Atmel products are not intended, authorized, or warranted for use as components in applications intended to support or sustain life.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Microchip:

[ATR4253C-PVPW-76](#) [ATR4253C-PVQW-76](#)